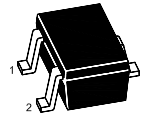
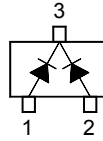


# MMBD202CCW

## Silicon Epitaxial Planar Switching Diode

### Application

- Ultra high speed switching



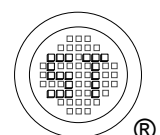
SOT-323 Plastic Package  
Marking Code: PH

### Absolute Maximum Ratings ( $T_a = 25\text{ }^\circ\text{C}$ )

Parameter	Symbol	Value	Unit
Maximum Peak Reverse Voltage	$V_{RM}$	80	V
Reverse Voltage	$V_R$	80	V
Average Forward Current	$I_{F(AV)}$	100	mA
Maximum Peak Forward Current	$I_{FM}$	300	mA
Non-repetitive Peak Forward Surge Current ( $t = 1\text{ }\mu\text{s}$ )	$I_{FSM}$	4	A
Power Dissipation	$P_d$	200	mW
Junction Temperature	$T_j$	150	$^\circ\text{C}$
Storage Temperature Range	$T_{stg}$	- 55 to + 150	$^\circ\text{C}$

### Characteristics at $T_a = 25\text{ }^\circ\text{C}$

Parameter	Symbol	Max.	Unit
Forward Voltage at $I_F = 100\text{ mA}$	$V_F$	1.2	V
Reverse Current at $V_R = 70\text{ V}$	$I_R$	0.1	$\mu\text{A}$
Total Capacitance at $V_R = 6\text{ V}$ , $f = 1\text{ MHz}$	$C_T$	3.5	pF
Reverse Recovery Time at $V_R = 6\text{ V}$ , $I_F = 5\text{ mA}$ , $R_L = 50\text{ }\Omega$	$t_{rr}$	4	ns



# MMBD202CCW

